

DP24H80/ μ A24H80 **Winchester Disk Servo Preamplifier**

General Description

The DP24H80/ μ A24H80 provides termination, gain, and impedance buffering for the servo read head in Winchester disk drives. It is a differential input, differential output design with fixed gain of approximately 100. The bandwidth is guaranteed greater than 30 MHz.

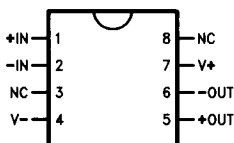
The internal design of the DP24H80/ μ A24H80 is optimized for low input noise voltage to allow its use in low input signal level applications. It is offered in 8-lead DIP, 10-lead flatpak, or SO-8 package suitable for surface mounting.

Features

- Low input noise voltage
- Wide power supply range (8V to 13V)
- Internal damping resistors (1.3 k Ω)
- Direct replacement for SSI 101A, with improved performance

Connection Diagrams

8-Lead DIP and SO-8 Package



Top View

Ceramic DIP

† Order Number μ A24H80RC

‡ See NS Package Number J08A

Molded Surface Mount

† Order Number μ A24H80SC

‡ See NS Package Number M08A

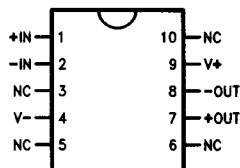
Molded DIP

† Order Number μ A24H80TC

‡ See NS Package Number N08E

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10-Lead Ceramic Flatpak



Top View

† Order Number μ A24H80FC

‡ See NS Package Number F10B

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Pin Descriptions

| Name | Description of Functions |
|-------|--|
| V + | Positive Differential Supply with Respect to V - |
| V - | Negative Differential Supply with Respect to V + |
| + IN | Positive Differential Input |
| - IN | Negative Differential Input |
| + OUT | Positive Differential Output |
| - OUT | Negative Differential Output |
| NC | No Connection |

† For most current order information, contact your local sales office.

‡ For current package information, contact product marketing.

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/Distributors for availability and specifications.

| | |
|--|-----------------|
| Storage Temperature Range | |
| Ceramic DIP and Flatpak | -65°C to +175°C |
| Molded DIP and SO-8 | -65°C to +150°C |
| Operating Temperature Range | |
| | 0°C to +70°C |
| Lead Temperature | |
| Ceramic DIP and Flatpak (Soldering, 60 seconds) | 300 °C |
| Molded DIP and SO-8 (Soldering, 10 seconds) | 265°C |

Internal Power Dissipation (Notes 1 & 2)

| | |
|----------------------------|-------|
| 8L-Ceramic DIP | 1.30W |
| 8L-Molded DIP | 0.93W |
| SO-8 | 0.81W |
| 10L-Flatpak | 0.79W |
| Supply Voltage | 15V |
| Output Voltage | 15V |
| Differential Input Voltage | ± 10V |

Note 1: $T_J \text{ MAX} = 150^\circ\text{C}$ for the Molded DIP and SO-8, and 175°C for the Ceramic DIP and Flatpak.

Note 2: Ratings apply to ambient temperature at 25°C . Above this temperature, derate the 8L-Ceramic DIP at $8.7 \text{ mW}/^\circ\text{C}$, the 8L-Molded DIP at $7.5 \text{ mW}/^\circ\text{C}$, the SO-8 at $6.5 \text{ mW}/^\circ\text{C}$, and the Flatpak at $5.3 \text{ mW}/^\circ\text{C}$.

Electrical Characteristics $T_A = 25^\circ\text{C}$, $V_{CC} = 8\text{V}$ to 13.2V , unless otherwise noted

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|---------------------|---|---|------|------|-----------|-------------------|
| G | Gain (Differential) (Note 4) | $R_p = 130\Omega$, $V_{CC} = 12\text{V}$ | 80 | 100 | 120 | |
| | | $R_p = 130\Omega$, $V_{CC} = 12\text{V}$ $T_A = 0^\circ\text{C}$ to $+70^\circ\text{C}$ | 70 | | 130 | |
| | | | | | | |
| BW | Bandwidth (3.0 dB) (Note 2) | $V_i = 0.5 \text{ mV}_{p-p}$ | 30 | 65 | | MHz |
| R_i | Input Resistance | | 1040 | 1300 | 1560 | Ω |
| C_i | Input Capacitance | | | 3 | | pF |
| V_i | Input Dynamic Range (Differential) | $R_p = 130\Omega$, $V_{CC} = 12\text{V}$ | 3 | | | mV_{p-p} |
| I_S | Supply Current | $V_{CC} = 12\text{V}$ | | 20 | 25 | mA |
| ΔV_O | Output Offset (Differential) | $R_p = 130\Omega$, $R_s = 0\Omega$ | | | 200 | mV |
| V_n | Equivalent Input Noise (Notes 2 & 3) | $R_s = 0\Omega$, $BW = 4 \text{ MHz}$ | | 1.5 | 2 | μV |
| PSRR | Power Supply Rejection Ratio (Note 1) | $R_s = 0\Omega$, $f = 5 \text{ MHz}$ | 55 | 70 | | dB |
| $\Delta G/\Delta V$ | Gain Sensitivity (Supply) | $R_p = 130\Omega$, $\Delta V_{CC} = \pm 10\%$ | | | ± 0.5 | %/V |
| $\Delta G/\Delta T$ | Gain Sensitivity (Temp) | $R_p = 130\Omega$, $T_A = 25^\circ\text{C}$ to $+70^\circ\text{C}$ | | -0.1 | | %/°C |
| CMR | Common Mode Rejection (Note 1) (Input) | $f = 5 \text{ MHz}$ | 60 | 75 | | dB |

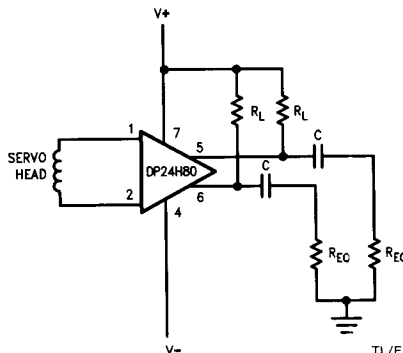
Note 1: Tested at DC, guaranteed at frequency.

Note 2: Guaranteed, but not tested in production.

Note 3: Equivalent input noise (additional specification):

| Typ | Max | Unit | Condition |
|------|-----|------------------------------|-------------------------|
| 3 | 4 | μV | $BW = 15 \text{ MHz}^2$ |
| 0.85 | 1.0 | $\text{nV}/\sqrt{\text{Hz}}$ | $BW = 15 \text{ MHz}^2$ |

Typical Applications



Note 1: Leads shown for 8-lead DIP.

Note 2: R_{eq} is equivalent load resistance.

$$\text{Note 3: } R_p = \frac{R_L \cdot R_{eq}}{R_L + R_{eq}}$$

Note 4: $G = 0.77 R_p$
Where $R_p =$ value from Note 3 (above) in ohms.

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